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# **Read Statement**

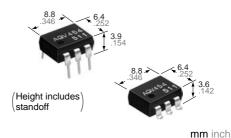
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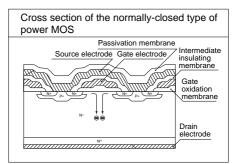
**Compliance with RoHS Directive** 

#### Normally closed DIP6-pin type Low on-resistance with 250V/400V load voltage

#### FEATURES

# 1. 1 Form B (Normally-closed) type with low on-resistance

This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Doublediffused and Selective Doping) method.



2. Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

#### 3. High sensitivity and low onresistance

c Standard type) c Standard type) (Standard type)

HE 1 Form B

(AQV450, AQV454H)

PhotoMOS Relays

Can control max. 0.2 A load current with 5 mA input current. Low on-resistance of typ. 5.5  $\Omega$  (AQV453).

# 4. Reinforced insulation 5,000 V type also available.

More than 0.4 mm .016 inch internal insulation distance between inputs and outputs. Conforms to IEC950 (reinforced insulation).

#### **TYPICAL APPLICATIONS**

- Security equipment
- High-speed inspection machines
- Measuring instruments
- Telephone equipment
- Sensing equipment

## TYPES

		Output rating*				Par	Packing quantity			
	I/O isolation			Package -	Through hole Surface-mount terminal					
		Load voltage	Load current		Tube packing style		Tape and reel packing style			
		voltage	current				Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel
AC/DC dual use	1,500 V AC	250 V	200 mA		AQV453	AQV453A	AQV453AX	AQV453AZ	1 tube contains:	1,000 pcs.
		400.1/ 450.	450	DIP6-pin	AQV454	AQV454A	AQV454AX	AQV454AZ	50 pcs. 1 batch contains:	
	Reinforced 5,000 V AC	400 V	150 mA		AQV454H	AQV454HA	AQV454HAX	AQV454HAZ	500 pcs.	

\* Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay.

## RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

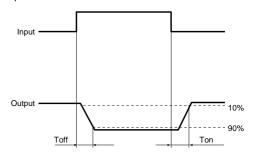
Item		Symbol	Type of connection	AQV453(A)	AQV454(A)	AQV454H(A)	Remarks
	LED forward current	IF		50 mA			
lanut	LED reverse voltage	Vr		5 V			
Input	Peak forward current	IFP			1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin			75 mW		
	Load voltage (peak AC)	VL		250 V	40	0 V	
		l.	А	0.2 A	0.15 A		A connection: Peak AC, DC B. C connection: DC
Output	Continuous load current		В	0.3 A	0.18 A		
Output			С	0.4 A	0.2	5 A	
	Peak load current	IPEAK	Ν	0.6 A	0.5 A		A connection: 100 ms (1 shot), $V_L = DC$
	Power dissipation	Ρουτ		360 mW			
Total power dissipation		Рт		410 mW 1,500 V AC 5,000 V AC			
I/O isolation voltage		Viso					
Temperature	Operating	Topr		-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures	
limits	Storage	Tstg		<b>−40°C to +100°C</b> −40°F to +212°F			

# HE 1 Form B (AQV45O, AQV454H)

#### 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV453(A)	AQV454(A)	AQV454H(A)	Remarks
lanut		Typical	Foff		1 mA	0.9 mA	1.4 mA	l∟ = Max.
	LED operate (OFF) current	Maximum	Foff		3 mA			$\neg$ IL = Max.
	LED reverse (ON) current	Minimum	Fon		0.4 mA			l⊾ = Max.
nput		Typical			0.9 mA	0.8 mA	1.3 mA	$\neg$ IL = Max.
	LED dropout voltage	Typical	VF	_	1.25 V (1.14 V at I⊧=5 mA)			I⊧ = 50 mA
	LED dropout voltage	Maximum	VF		1.5 V			
	On resistance	Typical	- Ron	A	5.5 Ω	11 Ω		I⊧ = 0 mA I∟= Max. Within 1 s on time
		Maximum			8Ω	16 Ω		
		Typical	- Ron	B	2.7 Ω	6.3 Ω		I⊧ = 0 mA I∟= Max. Within 1 s on time
Output		Maximum			4 Ω	8 Ω		
ouput		Typical	_	С	1.4 Ω	3.1 Ω		I⊧ = 0 mA I∟ = Max. Within 1 s on time
		Maximum	Ron		2 Ω	4 Ω		
	Off state leakage current	Maximum	Leak	_	1 μΑ	1 μΑ	10 µA	I⊧= 5 mA V∟= Max.
Transfer characteristics	Operate (OFF) time*	Typical	- T <sub>off</sub>	_	1.52 ms	1.2 ms	1.8 ms	$I_{\rm F} = 0 \text{ mA} \rightarrow 5 \text{ mA}$ $I_{\rm L} = \text{Max.}$
	Operate (OFF) time	Maximum			3 ms	2.0 ms	3.0 ms	
	Reverse (ON) time*	Typical	Ton		0.4 ms	0.36 ms	0.4 ms	$I_F = 5 \text{ mA} \rightarrow 0 \text{ m/s}$
		Maximum	Ion		1 ms			I∟ = Max.
	I/O capacitance	Typical	0		1.3 pF			f = 1 MHz Vв = 0 V
		Maximum	Ciso		3 pF			
	Initial I/O isolation resistance Minimu		Riso	—		1,000 MΩ		500 V DC

\*Operate/Reverse time



## **RECOMMENDED OPERATING CONDITIONS**

Please obey the following conditions to ensure proper relay operation and resetting.

		5	
Item	Symbol	Recommended value	Unit
Input LED current	lF	Standard type: 5 Reinforced insulation type: 5 to 10	mA

■ For Dimensions

For Schematic and Wiring Diagrams
For Cautions for Use

■ These products are not designed for automotive use.

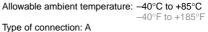
If you are considering to use these products for automotive applications, please contact your local Panasonic Electric Works technical representative.

For more information

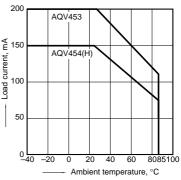
## HE 1 Form B (AQV45O, AQV454H)

### **REFERENCE DATA**

1. Load current vs. ambient temperature characteristics

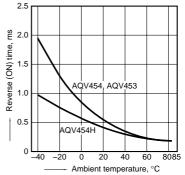




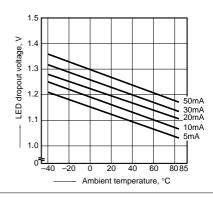


4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

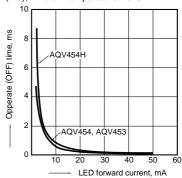


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



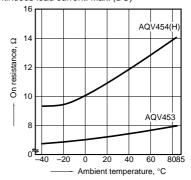
#### 10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°

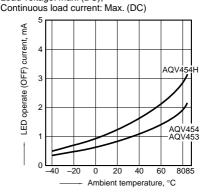


2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6: LED current: 0 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

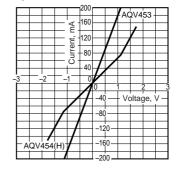


5. LED operate (OFF) current vs. ambient temperature characteristics Load voltage: Max. (DC);



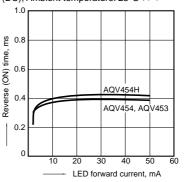
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



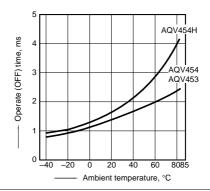
11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77

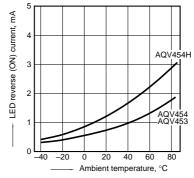


3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



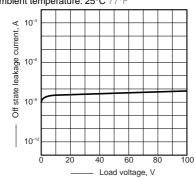
6. LED reverse (ON) current vs. ambient temperature characteristics Load voltage: Max. (DC); Continuous load current: Max. (DC)



9. Off state leakage current vs. load voltage characteristics

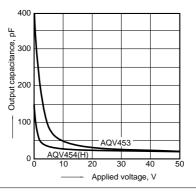
Sample: AQV454;

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



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